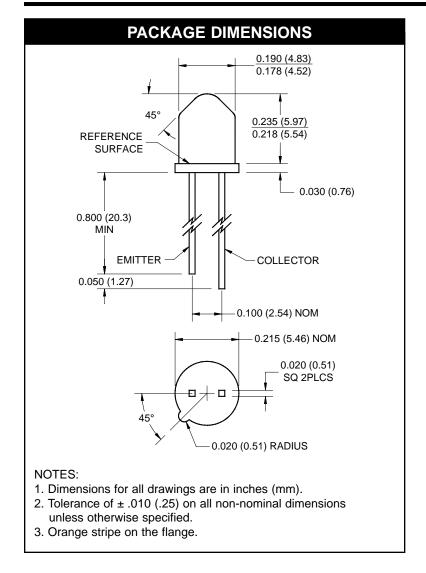
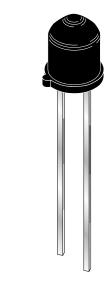
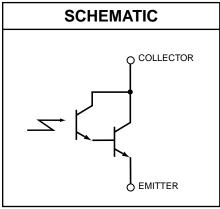
QSD733







DESCRIPTION

The QSD733 is a silicon phototdarlington encapsulated in an infrared transparent, black TO-18 package.

FEATURES

• NPN Silicon Photodarlington

• Package Type: Plastic TO-18

• Matched Emitter: QED523

• Narrow Reception Angle, 40°

Daylight Filter

· Package material and color: black epoxy

High Sensitivity



QSD733

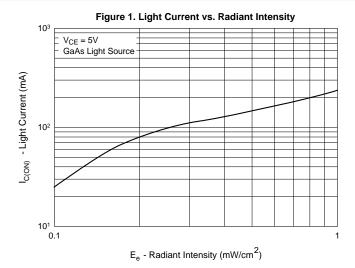
ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)						
Parameter	Symbol	Rating	Unit			
Operating Temperature	T _{OPR}	-40 to +100	°C			
Storage Temperature	T _{STG}	-40 to +100	°C			
Soldering Temperature (Iron)(2,3,4)	T _{SOL-I}	240 for 5 sec	°C			
Soldering Temperature (Flow)(2,3)	T _{SOL-F}	260 for 10 sec	°C			
Collector-Emitter Voltage	V _{CE}	30	V			
Emitter-Collector Voltage	V _{EC}	5	V			
Power Dissipation ⁽¹⁾	P _D	100	mW			

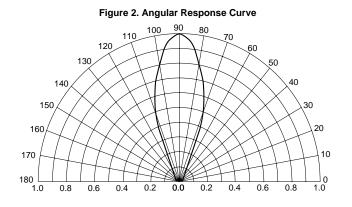
- 1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.
- 5. λ = 880 nm, AlGaAs.

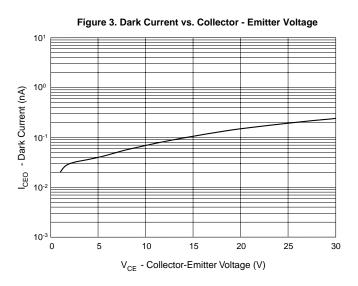
ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C)								
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS		
Peak Sensitivity Wavelength		λ_{PS}	_	880	_	nm		
Reception Angle		θ	_	±20	_	Deg.		
Collector-Emitter Dark Current	V _{CE} = 10 V, Ee = 0	I _{CEO}	_	_	100	nA		
Collector-Emitter Breakdown	$I_C = 1 \text{ mA}$	BV _{CEO}	30	_	_	V		
Emitter-Collector Breakdown	I _E = 100 μA	BV _{ECO}	5	_	_	V		
On-State Collector Current ⁽⁵⁾	$Ee = 0.125 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	Ic(on)	5.0	_	_	mA		
Saturation Voltage ⁽⁵⁾	$Ee = 0.125 \text{ mW/cm}^2$, $I_C = 2.0 \text{ mA}$	V _{CE(sat)}	_	_	1.0	V		
Rise Time	V EVD 100 O L 0.15 mA	t _r	_	20	_	μs		
Fall Time	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_C = 0.15 \text{ mA}$	t _f	_	50	_			

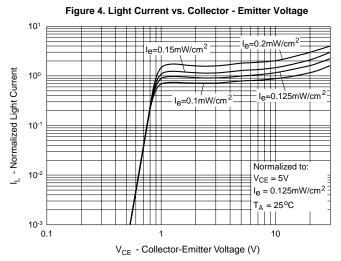


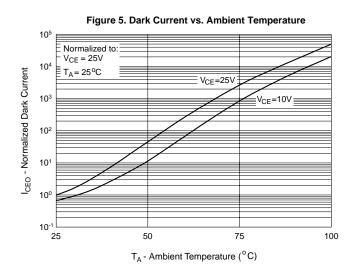
QSD733













QSD733

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.